

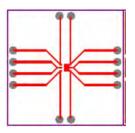
Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units
			V _{DSS} V _{GSS}	-20 ±12	V V
t<5s	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	ID	-12.8 -10.3	А	
Continuous Drain Current (Note 5) V_{GS} = -2.0V	Steady State	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	ID	-7.1 -6	А
	t<5s	$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	ID	-10 -8.3	А
Maximum Continuous Body Diode Forward Current (Note 5)			Is	-3	А
Pulsed Drain Current (10μ s pulse, duty cycle = 1%)			I _{DM}	-90	А
Avalanche Current (Note 6)			I _{AS}	17	А
Repetitive Avalanche Energy (Note 6)			E _{AS}	72	mJ

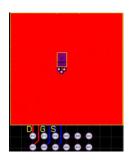
Thermal Characteristics

Characteristic		Symbol	Value	Units	
Total Bower Dissipation (Note 4)	$T_A = 25^{\circ}C$	Π-	1	W	
Total Power Dissipation (Note 4)	$T_A = 70^{\circ}C$	PD	0.63		
Thermal Resistance, Junction to Ambient (Note 4)	Steady State	P	126	°C/W	
	t<5s	$R_{ heta}JA$	60	C/W	
Total Power Dissipation (Note 5)	$T_A = 25^{\circ}C$	Р	2.1	W	
	T _A = 70°C	PD	1.3	vv	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	P	61		
mermai Resistance, Junction to Ambient (Note 5)	t<5s	$R_{ extsf{ heta}JA}$	29	°C/W	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	6.4			
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to 150	°C	

Notes: 4. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.



Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1 inch square copper plate



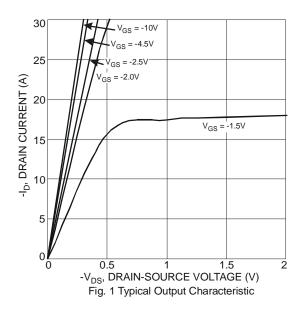


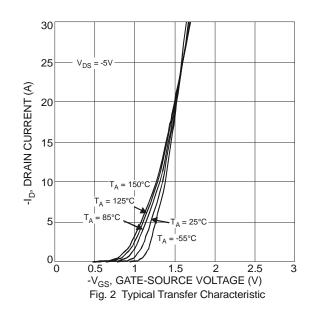
Electrical Characteristics @ T_A = 25°C unless otherwise stated

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Cymser		• 76	шах	0		
Drain-Source Breakdown Voltage	BV _{DSS}	-20	-	-	V	$V_{GS} = 0V, I_{D} = -10mA$	
Zero Gate Voltage Drain Current TJ = 25°C	IDSS	-	-	-1	μΑ	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±2	μΑ	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-0.45	-	-1.2	V	$V_{DS} = -10V, I_D = -200\mu A$	
Static Drain-Source On-Resistance		-	10	16	mΩ	V _{GS} = -4.5V, I _D = -3.6A	
	Б	-	12	20		V _{GS} = -2.5V, I _D = -3.6A	
	R _{DS (ON)}	-	13.6	25		V _{GS} = -2.0V, I _D = -1.8A	
		-	20	-		V _{GS} = -1.5V, I _D = -1A	
Forward Transfer Admittance	Y _{fs}	10	17	-	S	V _{DS} = -10V, I _D = -3.6A	
Diode Forward Voltage	V _{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = -3.6A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	-	4748	-		$V_{DS} = -10V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	Coss	-	833	-	pF		
Reverse Transfer Capacitance	C _{rss}	-	339	-			
Gate Resistance	R _g	-	6.2	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg	-	113	-		V _{DS} = -16V, I _D = -7.2A	
Total Gate Charge (V _{GS} = -4.5V)	Qg	-	53	-	nC		
Gate-Source Charge	Q _{qs}	-	7.1	-	nC		
Gate-Drain Charge	Q _{gd}	-	8.5	-			
Turn-On Delay Time	t _{D(on)}	-	22.8	-		$V_{DD} = -10V, V_{GS} = -4.5V,$ $R_G = 4.7\Omega, I_D = -3.6A$	
Turn-On Rise Time	tr	-	29.8	-			
Turn-Off Delay Time	t _{D(off)}	-	240.8	-	ns		
Turn-Off Fall Time	tf	-	100.6	-			

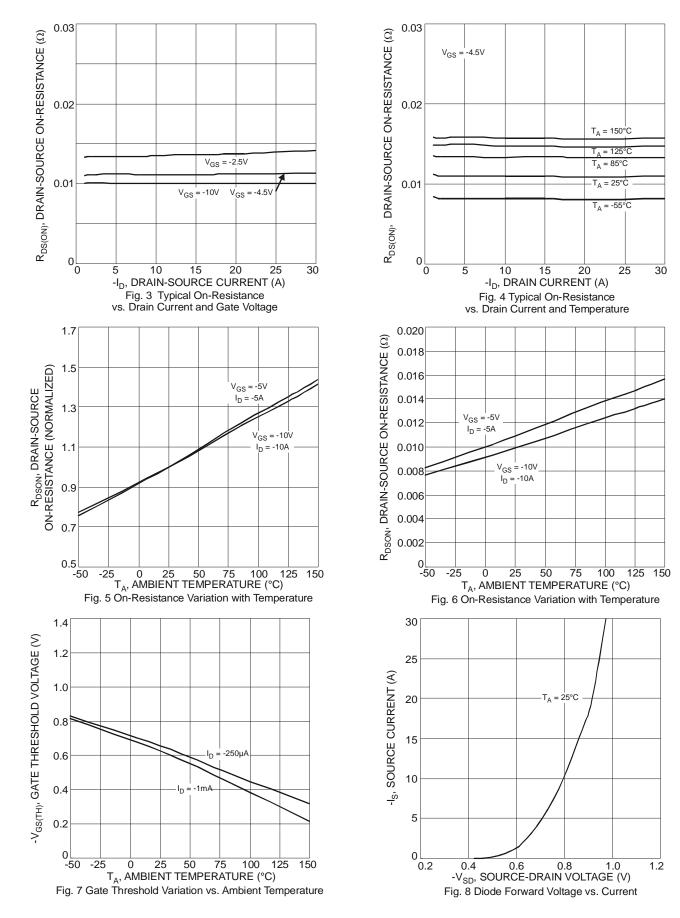
Notes:

6. UIS in production with L = 0.5mH, TJ = 25° C 7 .Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.





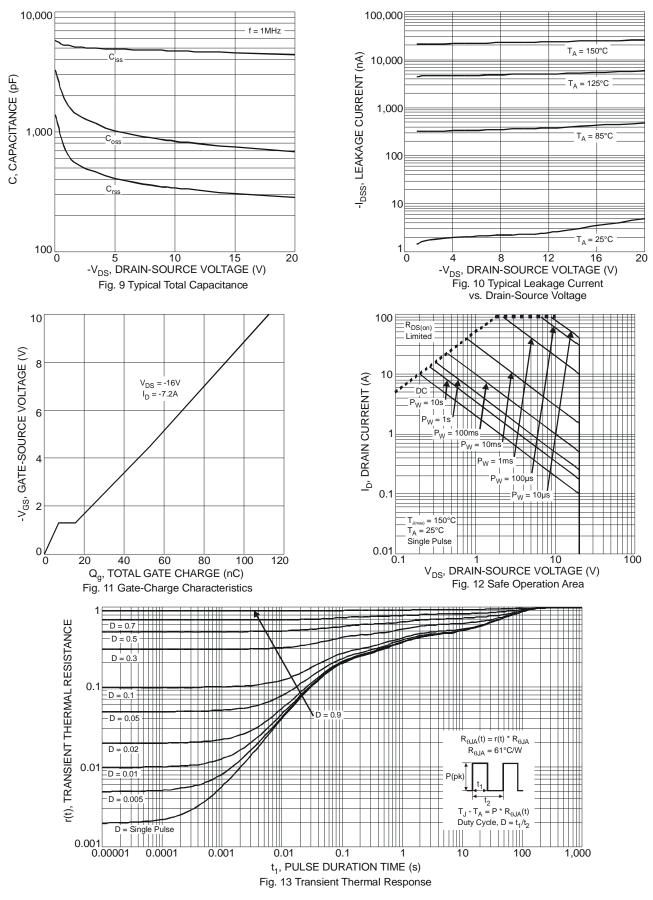




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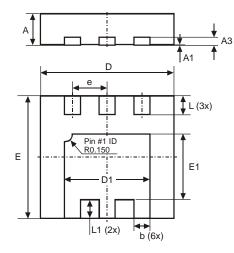
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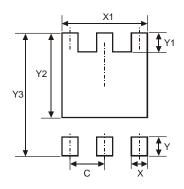


Package Outline Dimensions



U-DFN2523-6						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
A3	-	1	0.152			
b	0.25	0.35	0.30			
D	2.45	2.55	2.50			
D1	1.55	1.65	1.60			
e	-	-	0.65			
Е	2.25	2.35	2.30			
E1	1.18	1.28	1.23			
L	0.30	0.40	0.35			
L1	0.30	0.40	0.35			
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	1.700
Y	0.650
Y1	0.450
Y2	1.830
Y3	2.700



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